

Number	Hits	Search Text	DB	Time stamp
-	97	atomic adj layer adj epitax\$4 or atomic adj layer adj deposit\$4 or ale or ald and atomic adj layer adj deposit\$4 or epitax\$4 or ale or ald and dop\$4 and purg\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 11:47
-	11	atomic adj layer adj epitax\$4 or atomic adj layer adj deposit\$4 or ale or ald and atomic adj layer adj deposit\$4 or epitax\$4 or ale or ald and dop\$4 and purg\$4 and gallium adj nitride or gan	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 13:19
-	34	((atomic adj layer adj epitax\$4 or (atomic adj layer adj deposit\$4) or ale or ald) and ((atomic adj layer) adj (deposit\$4 or epitax\$4) or ale or ald) and dop\$4) and purg\$4 and (gallium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 13:13
-	97	puls\$4 near4 deposit\$4 same dop\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 13:14
-	58	((atomic adj layer) adj (deposit\$4 or epitax\$4) or ale or ald) same dop\$4) and gallium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 13:47
-	4	((((atomic adj layer) adj (deposit\$4 or epitax\$4)) or ale or ald) same dop\$4) and (TMGa or "cp.sub.2mg" or tesi)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 13:48
-	13	((((atomic adj layer) adj (deposit\$4 or epitax\$4)) or ale or ald) same dop\$4) and (trimethylgallium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 15:01
-	53	((((atomic adj layer) adj (deposit\$4 or epitax\$4)) or ale or ald) same (p\$1type or n\$1type or p\$1dop\$3 or n\$1dop\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 15:45
-	43	((((atomic adj layer) adj (deposit\$4 or epitax\$4)) or ale or ald) same (n\$1type or n\$1dop\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 15:29
-	99	((((atomic adj layer) adj (deposit\$4 or epitax\$4)) or ale or ald) same "III-V"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 15:29
-	10	suntola.in. and (ale or ald)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 15:39
-	35	super\$1lattice same ((p\$1type or p\$1dop\$4) and (n\$1dop\$3 or n\$1type)) same "III-V"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 17:25
-	13	tetraethylsilane same (si or silicon; same (impur\$4 or dop\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/04 17:31

-	50	gallium same magnesium same silicon same dop\$4 same n\$1type and p\$1type	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/04 17:39
-	51	gallium near\$1 p\$1type same silicon near\$4 dop\$4	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/04 17:46
-	54	gallium near\$1 p\$1type same dop\$3 near\$3 silicon same n\$1type	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/04 17:46
-	13	trimethylgallium or TMG or TMGa and ("cp.sub.2mg" or bicyclopentadienyl or magnesium) and ((atomic adj layer) adj (depost\$4 or epitax\$4)) or ale or ald	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/04 17:53
-	29	((atomic adj layer) adj (depost\$4 or epitax\$4)) or ale or ald same GAN	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/05 10:57
-	15	((atomic adj layer) adj (depost\$4 or epitax\$4)) or ale or ald same ((gallium adj nitride or gan) and (gallium adj arsenide or gaas))	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/05 13:10
-	13	((atomic adj layer) adj (depost\$4 or epitax\$4)) or ale or ald same ((gallium adj nitride or gan) and (gallium adj arsenide or gaas)) and dop\$4	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/05 15:26
-	23	(GAN or gallium adj nitride) same co\$1dop\$4	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/05 15:34
-	14	(GAN or gallium adj nitride) same co\$1dop\$4 same (mg or si or silicon or magnesium)	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/05 15:53
-	21	((dop\$4 or co\$1dop\$4) same ((mg or magnesium) and (si or silicon))) and (ale or ald)	USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM_TDB	2002/11/05 16:12